

1290 nm DFB Laser Diode, 5 mW

L1290P5DFB



Description

This 1290 nm, 5 mW, 2.5 Gbps, DFB laser diode is a Telcordia qualified product operable over a broad temperature range with a low temperature-wavelength coefficient. It is well suited for applications such as communications research, interferometry, and optical reflectometry for distance measurement in fiber or free space. Each device undergoes testing and burn-in.

This laser comes packaged in a 5.6 mm TO Can with D pin code. It contains an integrated aspheric focusing lens in the cap, allowing the focus spot and numerical aperture (NA) to be matched to SMF-28e+ fiber.

Specifications

Absolute Maximum Ratings ^a					
Specification	Symbol Maximum				
Maximum Power	P _{Max}	10 mW			
Forward Current	I _{FWD}	120 mA			
Operating Case Temperature	T_{Case}	-20 to +85 °C			
Storage Temperature	T_{Stor}	-40 to +100 °C			
Laser Reverse Bias	V_R	2 V			
Photodiode Reverse Bias	V_{RPD}	10 V			



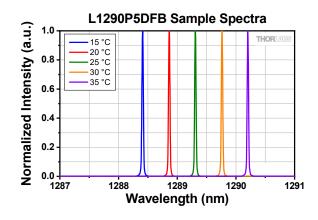
a. Absolute Maximum Rating specifications should never be exceeded. Operating at or beyond these conditions can permanently damage the laser.

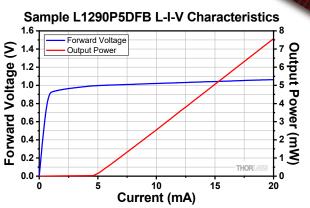
L1290P5DFB Specifications ^b					
	Symbol	Min	Тур.	Max	
	P _{op}	-	5 mW	-	
@ 25 °C	I	-	5 mA	13 mA	
@ 85 °C	ITH	-	30 mA	45 mA	
@ P _{op}	l _{op}	-	16 mA	40 mA	
l.	V_{op}	-	1.0 V	1.6 V	
	η	-	0.48 W/A	-	
op.	λο	1287 nm	1290 nm	1293 nm	
3)	Δλ	-	0.1 nm	-	
re Coefficient	Δλ/ΔΤ	-	0.09 nm/°C	-	
Ratio	SMSR	35 dB	40 dB	-	
Parallel @ Pop	ΘΠ	-	7 °	-	
erpendicular @ P _{op}	$ heta_{\perp}$	-	9°	-	
.0% to 80%)	t _R , t _F	-	•	0.1 ns	
	I _{PD}	100 μΑ	-	1000 μΑ	
ving)		7.0 mm	7.5 mm	8.0 mm	
ameter)	Фғ	-	12.7 µm	-	
	@ 25 °C @ 85 °C @ Pop Dop Dop The Coefficient Ratio	$\begin{array}{c c} & & & & \\ & & & & \\ & & & \\ \hline & & & & \\ \hline & & & &$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

b. $T_{CASE} = 25$ °C if not specified.

THORLABS

Performance Plots





Drawing

